





#### 20V PNP LOW SATURATION SWITCHING TRANSISTOR

#### **Features and Benefits**

- BV<sub>CEO</sub> > -20V
- I<sub>C</sub> = -3.5A Continuous Collector Current
- Low Saturation Voltage (-220mV max @ -1A)
- R<sub>SAT</sub> = 64 mΩ for a low equivalent On-Resistance
- hFE specified up to -6A for high current gain hold up
- Low profile 0.6mm high package for thin applications
- R<sub>θ</sub>JA efficient, 60% lower than SOT23
- 4mm<sup>2</sup> footprint, 50% smaller than SOT23
- Lead-Free, RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

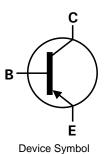
### **Mechanical Data**

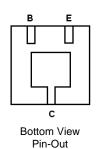
- Case: DFN2020B-3
- Case Material: Molded Plastic. "Green" Molding Compound.
- Terminals: Pre-Plated NiPdAu leadframe.
- Nominal Package Height: 0.6mm
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 0.01 grams (approximate)

### **Applications**

- MOSFET Gate Driving
- DC-DC Converters
- Charging Circuits
- Power switches
- Motor control







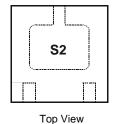
### Ordering Information (Note 3)

Ξ					
Г	Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
I	ZXTP718MATA	S2	7	8	3000
	ZXTP718MATC	S2	13	8	10000

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com
- 3. For Packaging Details, go to our website at http://www.diodes.com.

### **Marking Information**



S2 = Product Type Marking code





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Characteristic		Symbol	Value	Unit	
Collector-Base Voltage		V <sub>CBO</sub>	-25		
Collector-Emitter Voltage		$V_{CEO}$	-20	V	
Emitter-Base Voltage		V <sub>EBO</sub>	-7		
Peak Pulse Current		I <sub>CM</sub>	-6		
Continuous Collector Current	(Note 4)	I-	-3.5	^	
Continuous Collector Current	(Note 5)	IC	-4.0	^	
Base Current		I <sub>B</sub>	-1		

### Thermal Characteristics @TA = 25°C unless otherwise specified

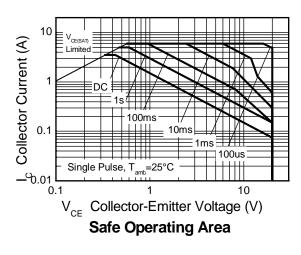
Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 4)	9	1.5 12	W
Linear Derating Factor	(Note 5)	P <sub>D</sub>	2.45 19.6	mW/°C
Thermal Decistores Junction to Ambient	(Note 4)		83	
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	51	°C/W
Thermal Resistance, Junction to Lead	(Note 6)	$R_{ heta JL}$	16.8	
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

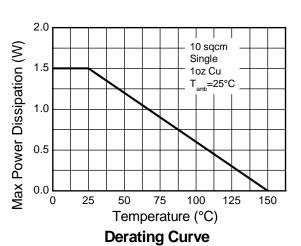
Notes:

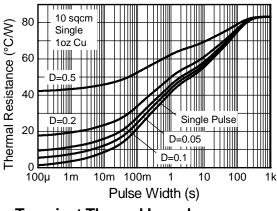
- 4. For a device surface mounted on 31mm x 31mm (10cm²) FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition. The entire exposed collector pad is attached to the heatsink.
- 5. Same as note (3), except the device is measured at t ≤ 5 sec.
- 6. For a single device, thermal resistance from junction to solder-point (at the end of the drain lead).

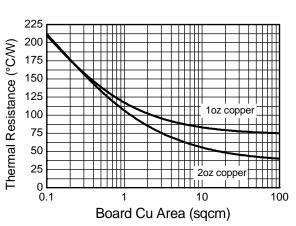


### **Thermal Characteristics**



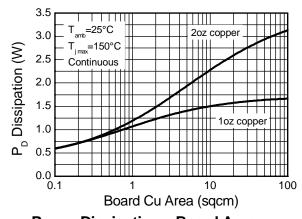






### **Transient Thermal Impedance**

Thermal Resistance v Board Area



Power Dissipation v Board Area





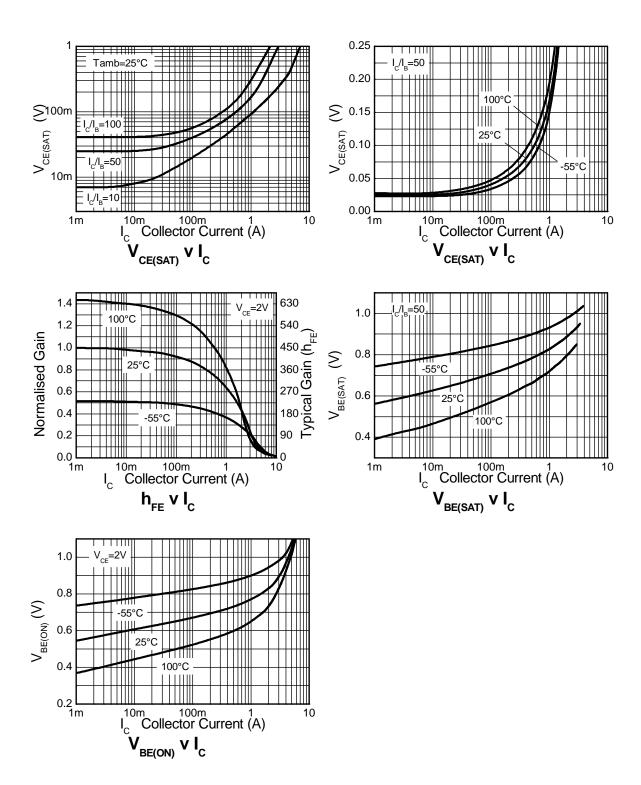
## Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-25	-35	-	V	$I_C = -100  \mu A$
Collector-Emitter Breakdown Voltage (Note 7)	BV <sub>CEO</sub>	-20	-25	-	V	I <sub>C</sub> = -10 mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-8.5	-	V	I <sub>E</sub> = -100 μA
Collector Cutoff Current	I <sub>CBO</sub>	-	-	-100	nA	V <sub>CB</sub> = -20V
Emitter Cutoff Current	I <sub>EBO</sub>	-	-	-100	. nA	$V_{EB} = -6V$
Collector Emitter Cutoff Current	I <sub>CES</sub>	-	-	-100	nA	V <sub>CES</sub> = -16V
Static Forward Current Transfer Ratio (Note 7)	h <sub>FE</sub>	300 300 150 15	475 450 230 30	- - -	-	$I_{C}$ = -10mA, $V_{CE}$ = -2V $I_{C}$ = -100mA, $V_{CE}$ = -2V $I_{C}$ = -2A, $V_{CE}$ = -2V $I_{C}$ = -6A, $V_{CE}$ = -2V
Collector-Emitter Saturation Voltage (Note 7)	V <sub>CE</sub> (sat)	- - - -	-19 -170 -190 -240 -225	-30 -220 -250 -350 -300	mV	$I_C = -0.1A$ , $I_B = -10mA$ $I_C = -1A$ , $I_B = -20mA$ $I_C = -1.5A$ , $I_B = -50mA$ $I_C = -2.5A$ , $I_B = -150mA$ $I_C = -3.5A$ , $I_B = -350mA$
Base-Emitter Turn-On Voltage (Note 7)	V <sub>BE(on)</sub>	-	-0.87	-0.95	V	$I_C = -3.5A$ , $V_{CE} = -2V$
Base-Emitter Saturation Voltage (Note 7)	V <sub>BE(sat)</sub>	-	-1.01	-1.120	V	$I_C = -3.5A$ , $I_B = -350mA$
Output Capacitance	C <sub>obo</sub>	-	21	30	pF	V <sub>CB</sub> =-10V. f = 1MHz
Transition Frequency	f <sub>T</sub>	150	180	-	MHz	$V_{CE} = -10V, I_{C} = -50mA,$ f = 100MHz
Turn-On Time	t <sub>on</sub>	-	40	-	ns	$V_{CC} = -10V, I_{C} = -1A$
Turn-Off Time	t <sub>off</sub>	-	670	-	ns	$I_{B1} = I_{B2} = -10 \text{mA}$

Notes: 7. Measured under pulsed conditions. Pulse width  $\leq$  300  $\mu$ s. Duty cycle  $\leq$  2%.

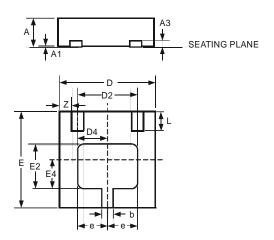


## **Typical Electrical Characteristics**



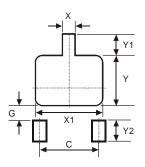


## **Package Outline Dimensions**



DFN2020B-3						
Dim	Min	Max	Тур			
Α	0.57	0.63	0.60			
A1	0	0.05	0.02			
A3	_	_	0.152			
b	0.20	0.30	0.25			
D	1.95	2.075	2.00			
D2	1.22	1.42	1.32			
D4	0.56	0.76	0.66			
е	_	_	0.65			
Е	1.95	2.075	2.00			
E2	0.79	0.99	0.89			
E4	0.48	0.68	0.58			
L	0.25	0.35	0.30			
Z	_	_	0.225			
All Dimensions in mm						

## **Suggested Pad Layout**



Dimensions	Value (in mm)
С	1.30
G	0.24
Х	0.35
X1	1.52
Υ	1.09
Y1	0.47
Y2	0.50





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